



## MMBT7002KDW Plastic-Encapsulate MOSFETS

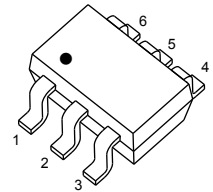
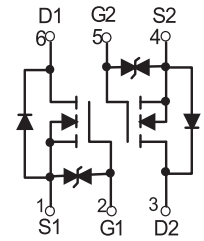
### APPLICATION

- Load Switch for Portable Devices
- DC/DC Converter

### FEATURE

- High density cell design for Low  $R_{DS(on)}$
- Voltage controlled small signal switch
- Rugged and reliable
- High saturation current capability
- ESD protected

MARKING 72K



SOT-363

### MOSFET MAXIMUM RATINGS ( $T_a = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
$V_{DS}$	Drain-Source voltage	60	V
$V_{GS}$	Gate-Source voltage	$\pm 20$	V
$I_D$	Drain Current	300	mA
$P_D$	Power Dissipation	0.15	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-55-150	$^\circ\text{C}$
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	833	$^\circ\text{C}/\text{W}$



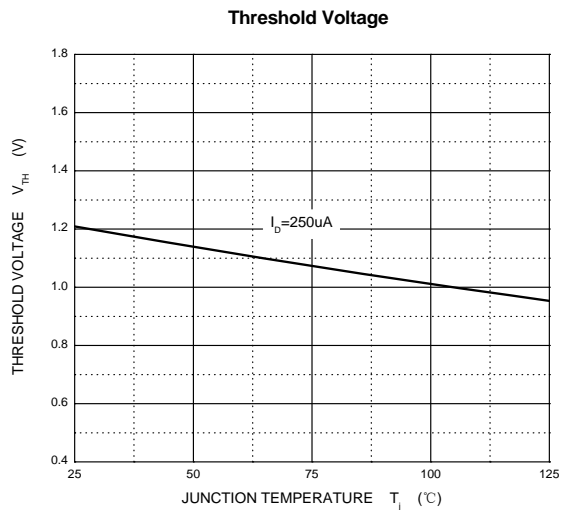
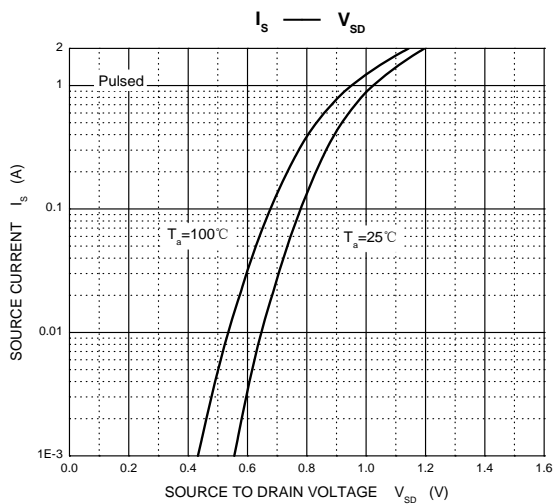
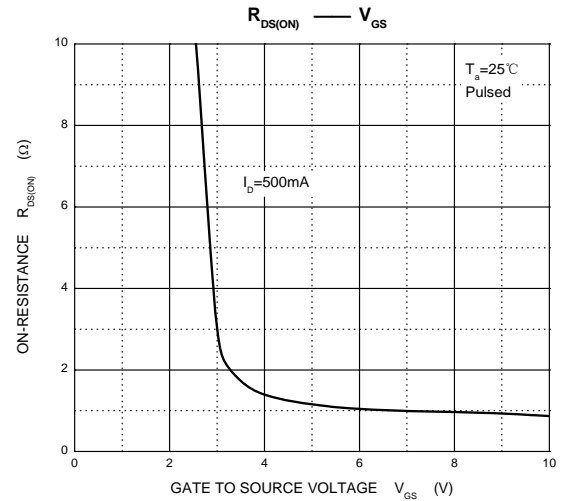
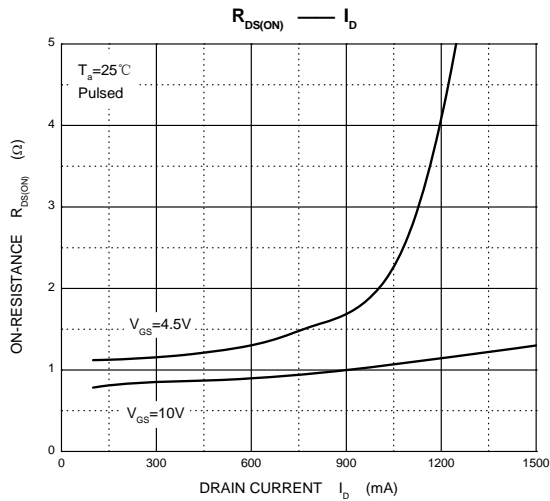
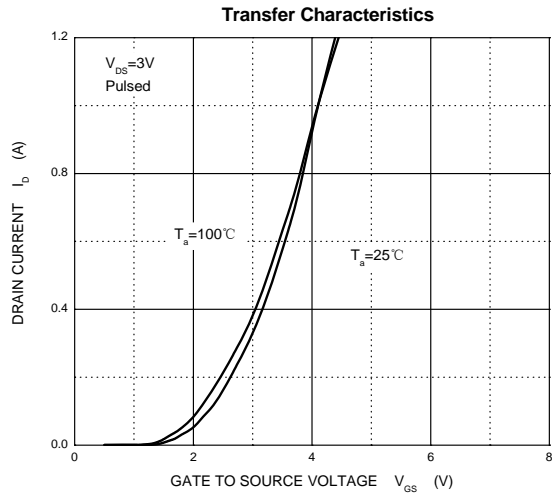
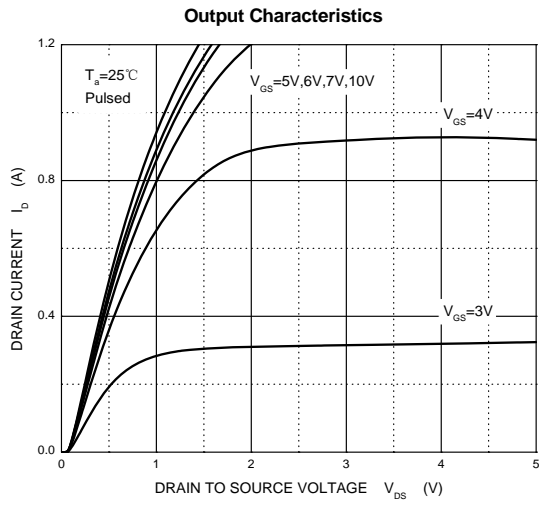
$T_a=25\text{ }^\circ\text{C}$  unless otherwise specified

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
<b>Static Characteristics</b>						
Drain-Source Breakdown Voltage	$V_{DS}$	$V_{GS} = 0V, I_D = 250\mu A$	60			V
Gate Threshold Voltage*	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 1mA$	1	1.3	2.5	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 48V, V_{GS} = 0V$			1	$\mu A$
Gate –Source leakage current	$I_{GSS1}$	$V_{GS} = \pm 20V, V_{DS} = 0V$			$\pm 10$	$\mu A$
Drain-Source On-Resistance*	$R_{DS(on)}$	$V_{GS} = 4.5V, I_D = 200mA$		1.1	5.3	$\Omega$
		$V_{GS} = 10V, I_D = 500mA$		0.9	5	$\Omega$
Diode Forward Voltage	$V_{SD}$	$V_{GS} = 0V, I_S = 300mA$			1.5	V
Recovered charge	$Q_r$	$V_{GS} = 0V, I_S = 300mA, V_R = 25V, di_S/dt = -100A/\mu s$		30		nC
<b>Dynamic Characteristics**</b>						
Input Capacitance	$C_{iss}$	$V_{DS} = 10V, V_{GS} = 0V, f = 1MHz$			40	pF
Output Capacitance	$C_{oss}$				30	pF
Reverse Transfer Capacitance	$C_{rss}$				10	pF
<b>Switching Characteristics**</b>						
Turn-On Delay Time	$t_{d(on)}$	$V_{GS} = 10V, V_{DD} = 50V, R_G = 50\Omega, R_{GS} = 50\Omega, R_L = 250\Omega$			10	ns
Turn-Off Delay Time	$t_{d(off)}$				15	ns
Reverse recovery Time	$t_{rr}$	$V_{GS} = 0V, I_S = 300mA, V_R = 25V, di_S/dt = -100A/\mu s$		30		ns
<b>GATE-SOURCE ZENER DIODE</b>						
Gate-Source Breakdown Voltage	$BV_{GSO}$	$I_{GS} = \pm 1mA$ (Open Drain)	$\pm 21.5$		$\pm 30$	V

**Notes :**

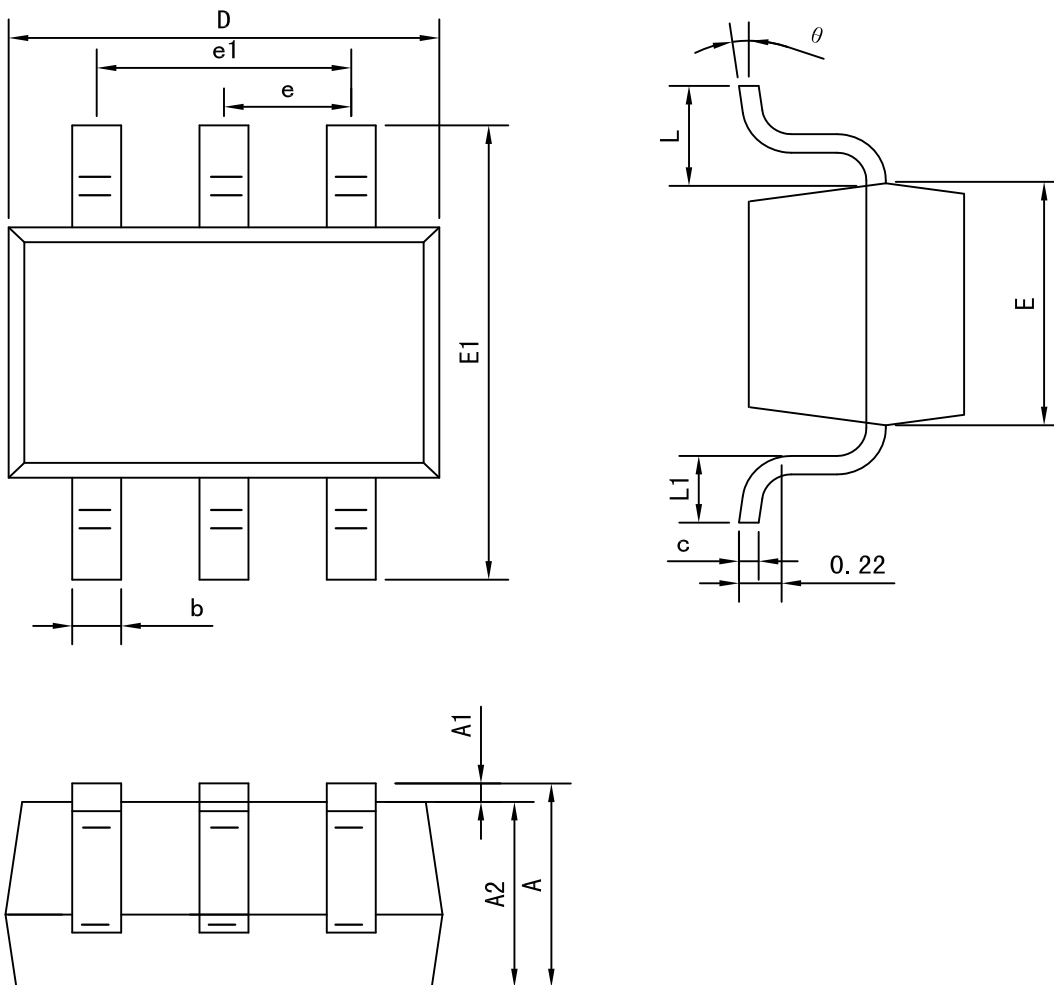
\*Pulse Test : Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$ .

\*\*These parameters have no way to verify.





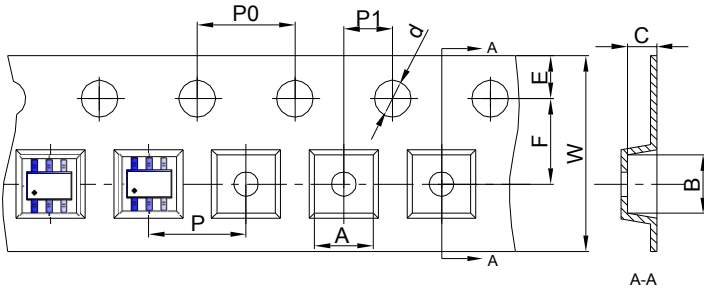
## SOT-363 Package outline dimensions



Symbol	Dimension in Millimeters	
	Min	Max
A	0.900	1.100
A1	0.000	0.100
A2	0.900	1.000
b	0.150	0.350
c	0.080	0.150
D	2.000	2.200
E	1.150	1.350
E1	2.150	2.450
e	0.650 TYP	
e1	1.200	1.400
L	0.525 REF	
L1	0.260	0.460
$\theta$	0°	8°



### SOT-363 Embossed Carrier Tape



**Packaging Description:**  
 SOT-363 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 17.8cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-363	2.25	2.55	1.20	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

### SOT-363 Tape Leader and Trailer

